



# PHOTONICS Research

## Efficient mid-infrared single-photon detection using superconducting NbTiN nanowires with high time resolution in a Gifford-McMahon cryocooler

JIN CHANG,<sup>1,2,\*</sup> JOHANNES W. N. LOS,<sup>2</sup> RONAN GOURGUES,<sup>2</sup>  STEPHAN STEINHAEUER,<sup>3</sup> S. N. DORENBOS,<sup>2</sup> SILVANIA F. PEREIRA,<sup>1</sup> H. PAUL URBACH,<sup>1</sup> VAL ZWILLER,<sup>3</sup> AND IMAN ESMAEIL ZADEH<sup>1</sup> 

<sup>1</sup>Optics Research Group, ImPhys Department, Faculty of Applied Sciences, Delft University of Technology, Delft 2628 CJ, The Netherlands

<sup>2</sup>Single Quantum B.V., Delft 2628 CJ, The Netherlands

<sup>3</sup>KTH Royal Institute of Technology, Department of Applied Physics, Albanova University Centre, 106 91 Stockholm, Sweden

\*Corresponding author: j.chang-1@tudelft.nl

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Shortly after their inception, superconducting nanowire single-photon detectors (SNSPDs) became the leading quantum light detection technology. With the capability of detecting single-photons with near-unity efficiency, high time resolution, low dark count rate, and fast recovery time, SNSPDs outperform conventional single-photon detection techniques. However, detecting lower energy single photons ( $<0.8$  eV) with high efficiency and low timing jitter has remained a challenge. To achieve unity internal efficiency at mid-infrared wavelengths, previous works used amorphous superconducting materials with low energy gaps at the expense of reduced time resolution (close to a nanosecond), and by operating them in complex milliKelvin (mK) dilution refrigerators. In this work, we provide an alternative approach with SNSPDs fabricated from 5 to 9.5 nm thick NbTiN superconducting films and devices operated in conventional Gifford-McMahon cryocoolers. By optimizing the superconducting film deposition process, film thickness, and nanowire design, our fiber-coupled devices achieved  $>70\%$  system detection efficiency (SDE) at  $2\ \mu\text{m}$  and sub-15 ps timing jitter. Furthermore, detectors from the same batch demonstrated unity internal detection efficiency at  $3\ \mu\text{m}$  and  $80\%$  internal efficiency at  $4\ \mu\text{m}$ , paving the road for an efficient mid-infrared single-photon detection technology with unparalleled time resolution and without mK cooling requirements. We also systematically studied the dark count rates (DCRs) of our detectors coupled to different types of mid-infrared optical fibers and blackbody radiation filters. This offers insight into the trade-off between bandwidth and DCRs for mid-infrared SNSPDs. To conclude, this paper significantly extends the working wavelength range for SNSPDs made from polycrystalline NbTiN to  $1.5\text{--}4\ \mu\text{m}$ , and we expect quantum optics experiments and applications in the mid-infrared range to benefit from this far-reaching technology.

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### 1. INTRODUCTION

Detecting light at the single-photon level has enabled novel scientific and industrial applications in recent decades [1]. Specifically, near- and mid-infrared detection is crucial for areas such as infrared fluorescence and spectroscopy [2–4], semiconductor and industrial production monitoring [5,6], planetary soil studies [7], remote light detection and ranging [8], as well as two-photon entanglement and interference [9] experiments. However, since photon energy is inversely proportional

to wavelength, detecting long wavelength photons is intrinsically more challenging than detecting shorter wavelength photons. Generally, Si-based detectors can be used for infrared detection but suffer from a low cutoff wavelength, typically around  $1.1\ \mu\text{m}$  [10], making them inefficient for long wavelength photon detection. Si:Sb-based impurity band conduction detectors show mid-infrared light detection capability but not at the single-photon level [11]. Similarly, narrow-bandgap photoconductive semiconductors, like HgCdTe,

InAs, and InGaAs detectors, suffer from low efficiency, large dark counts, and poor time resolution [12]. In contrast, superconducting nanowire single-photon detectors (SNSPDs) have high detection efficiency [13–15], high detection rates [16], low dark count rates (DCRs) [17], fast recovery time [18], and unprecedented temporal resolution [19,20], and thus they outperform traditional infrared single-photon detectors.

In 2001, NbN-based SNSPDs were first demonstrated by detecting 810 nm single photons [21]. Subsequently, SNSPDs fabricated on different platforms were explored and developed [1]. Although high system detection efficiencies have been realized and reported for the UV [22], visible [23], and near-infrared/telecom [13–15,24] ranges, detecting single photons beyond 1550 nm with high efficiency and time resolution has remained a challenge [25]. Early works showed amorphous WSi-based SNSPDs could be used for mid-infrared detection. However, these studies employed 4–6 nm thin superconducting films, resulting in low critical currents, which is detrimental to the timing jitter. The reported temporal resolution was close to the nanosecond scale [26], and these devices must be operated at sub-Kelvin temperatures, requiring complex dilution refrigerators. NbN-based SNSPDs with ultranarrow linewidths showed sensitivity up to 5  $\mu\text{m}$  (saturated internal efficiency until 2.7  $\mu\text{m}$ ) [27]. A consequence of squeezing the nanowire width to around 30 nm makes fabrication challenging and degrades the detectors' time resolution with the reduced critical current. In short, different works toward achieving efficient mid-infrared single-photon detection are summarized in Table 1 below.

Alternatively, our previous work [31] showed that by optimizing the stoichiometry of polycrystalline NbTiN film during reactive magnetron co-sputtering deposition, it is possible to make SNSPDs with strongly saturated efficiency plateaus in the near-infrared region at 2.8 K operating temperature and also high performance at visible wavelengths up to 7 K [32]. Also, relatively thick NbTiN superconducting films were used [19,33] to improve our detectors' optical absorption and critical current, therefore enhancing efficiency and time resolution. Building on our previous results, in this work we made SNSPDs from 5, 6.5, 7.5, and 9.5 nm thick NbTiN films with different nanowire designs. First, by characterizing our SNSPDs using flood illumination, we optimized the meander design in terms of internal detection efficiency. Encouraged by our initial characterization results, we fabricated fiber-coupled SNSPDs and achieved a system detection efficiency of >70% at 2  $\mu\text{m}$  in Gifford-McMahon (GM) cryocoolers (2.4–2.8 K). Broadband detectors were also demonstrated with >50%

system detection efficiency (SDE) over the entire 1550–2000 nm range with sub-15 ps timing jitter. Furthermore, devices made from 7.5 and 6.5 nm films showed unity internal detection efficiency at 3  $\mu\text{m}$  and 80% internal efficiency at 4  $\mu\text{m}$ . We also systematically studied the DCRs from the detector itself (intrinsic DCRs) and from blackbody radiation delivered by different types of fibers as well as coated fibers as a technique to reduce the DCR. These results offer a comprehensive understanding of the origin of dark counts in mid-infrared SNSPD systems.

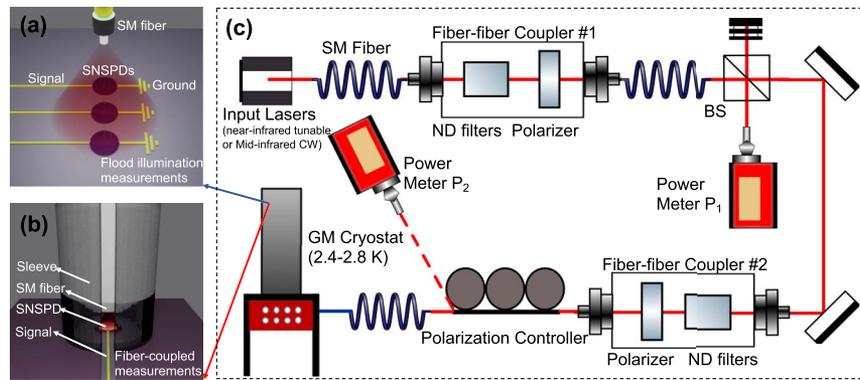
## 2. SNSPD FABRICATION AND MEASUREMENT SETUP

Similar to Ref. [31], we deposited superconducting NbTiN films by a reactive magnetron co-sputtering deposition process. The stoichiometry of the films was controlled by adjusting the sputtering powers on the Ti and Nb targets. Film thickness was determined by a calibrated crystal microbalance, and SNSPDs were fabricated as described in Ref. [19]. Our fabricated detectors were either tested under flood illumination [Fig. 1(a)] or etched into a keyhole die shape and packaged using a standard ferrule and mating sleeves approach [34] [Fig. 1(b)]. This coupling method guarantees automatic alignment between detector and optical fibers for accurate system efficiency measurements. Both the flood illumination and fiber-coupled setup are shown in Fig. 1(c).

As shown in Fig. 1(c), we employ a near-infrared tunable laser (JGR-TLS5, 1260–1650 nm) and mid-infrared CW lasers with different wavelengths (2000 and 2700 nm laser from Thorlabs, 3001 and 4013 nm laser from Nanoplus) as input photon sources. Single-mode optical fibers are used to couple the light to the first fiber-to-fiber coupler (containing neutral density filters and a polarizer). A beam splitter is then used to create a reference arm with the majority of the power coupled to a calibrated power meter,  $P_1$ . The signal beam with the lowest power is sent to the second fiber-to-fiber coupler, also containing a polarizer and neutral density filters. A polarization controller is used to tune the polarization state of the light after the second fiber-to-fiber coupler. After recording the light power intensity emerging from the polarization controller with power meter,  $P_2$ , the light is guided to the system to carry out either flood illumination or fiber-coupled measurements. For flood illumination measurements, the input light is heavily attenuated to the single-photon regime. This is verified by the fact that the detectors' count rate increased linearly with the increase of the input laser power. Also, the total photon flux reaching the detector is estimated to be in the order of

**Table 1. Comparison of Different Mid-Infrared SNSPD Works**

Materials	Linewidth/Film Thickness (nm)	Operation Temperature	Wavelength ( $\mu\text{m}$ )	SDE (2 $\mu\text{m}$ )/Jitter (ps)	Reference
$\text{Mo}_{0.8}\text{Si}_{0.2}$	30/6	80 mK	1.55–5.07	Unknown	[28]
WSi	50/3.2	850 mK	4.8–9.9	Unknown	[29]
WSi	100/3.5	400 mK	1.5–6	<1%/600	[26]
NbN	30/5.5	1.5 K	0.5–5	5%/unknown	[27]
NbN	56/6	2.25 K	1.55–2	63%/102	[30]
NbTiN	40–60/7.5–9.5	2.5–2.8 K	1.55–4	70%/14.3	This work



**Fig. 1.** Illustration of (a) detector flood illumination, (b) a fiber-coupled detector, and (c) schematic of the efficiency measurement setup.

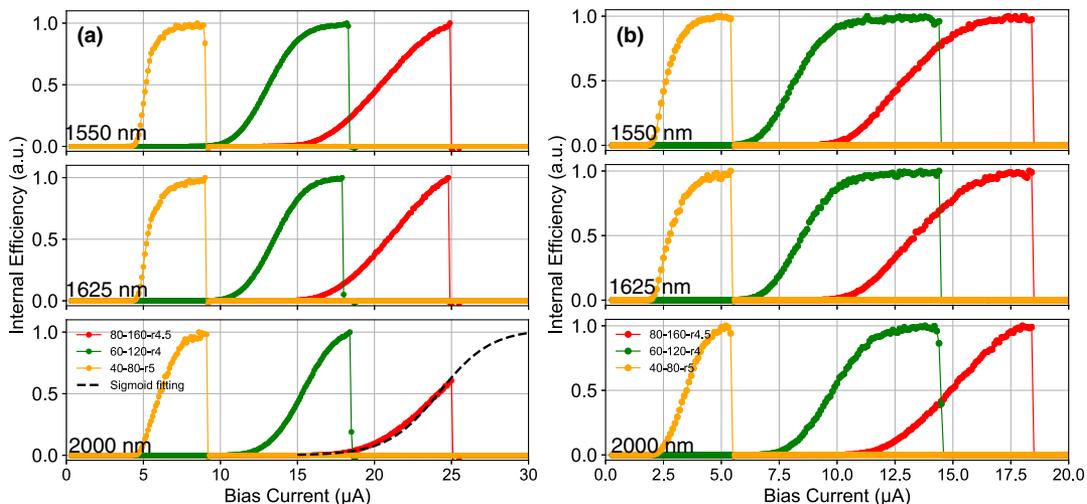
1–10 nW with 50 dB attenuation; according to the Poissonian photon statistics of attenuated laser light, the single-photon event is dominant under such illumination condition. For fiber-coupled device measurements we use the following procedure: we first set the ratio  $P_1/P_2$  to 50 dB by placing neutral density (ND) filters in both fiber-to-fiber couplers, and then add additional ND filters to the first coupler to reach  $P_{in} = 10$  nW at the first power meter. In this way, the input photon flux can be back calculated. For example, 10 nW ( $P_{in}$ ) with 50 dB ( $P_1/P_2$ ) attenuation at 2000 nm corresponds to an input photon flux of  $1.006 \times 10^6$  photons per second. More measurement details can be found in our previous work [14].

### 3. CHARACTERIZATION OF SNSPDs WITH FLOOD ILLUMINATION

In this work, SNSPDs with different nanowire widths (40/60/80 nm) and diameters (8/9/10  $\mu$ m) were fabricated from 5 to 9.5 nm thick NbTiN films. For example, 60-120-r4 refers to a meandering nanowire design with 60 nm wide lines, a pitch of 120 nm, and 4  $\mu$ m radius [see insert in Fig. 3(b)].

As shown in Fig. 2(a), at 1550 and 1625 nm, the 40 nm wide device (yellow), 60 nm wide device (green), and 80 nm wide device (red) all showed saturated internal efficiencies.

When the laser wavelength was increased to 2000 nm, the 40 and 60 nm wide nanowires (yellow and green) devices maintained saturated internal efficiencies, while the 80 nm wide nanowire device (red curve) does not reach unity internal efficiency. To obtain greater saturated internal efficiency, one possible solution is to make narrower lines. However, with narrower linewidth (<40 nm) the nanofabrication patterning, development, and etching become more critical. This will, in general, affect the fabrication yield. Alternatively, we sputtered 7.5 nm thick NbTiN films and made detectors with the same designs and nanofabrication process. As shown in Fig. 2(b), by using 7.5 nm thick NbTiN film, all devices with linewidths ranging from 40 to 80 nm showed unity internal efficiency at 2000 nm. Detailed performance of devices based on 9.5 and 7.5 nm films is summarized in Table 2. A thinner film leads to lower critical currents (for the same meander design), and timing jitter is thus higher because the output pulse has a lower signal-to-noise ratio [35]. The rise time (time interval for signal to go from 20% to 80% of the pulse amplitude) of the devices on 7.5 nm NbTiN was longer than for the 9.5 nm devices and the dead time (width of pulse at level of 1/e of the amplitude) was also slightly longer. This can be explained by the fact that devices made with thinner films have higher kinetic inductance.



**Fig. 2.** Internal efficiency measurements of SNSPDs fabricated from (a) 9.5 nm and (b) 7.5 nm thick NbTiN films.

**Table 2. Flood Illumination Measurement Results of 9.5 and 7.5 nm NbTiN-Based SNSPDs**

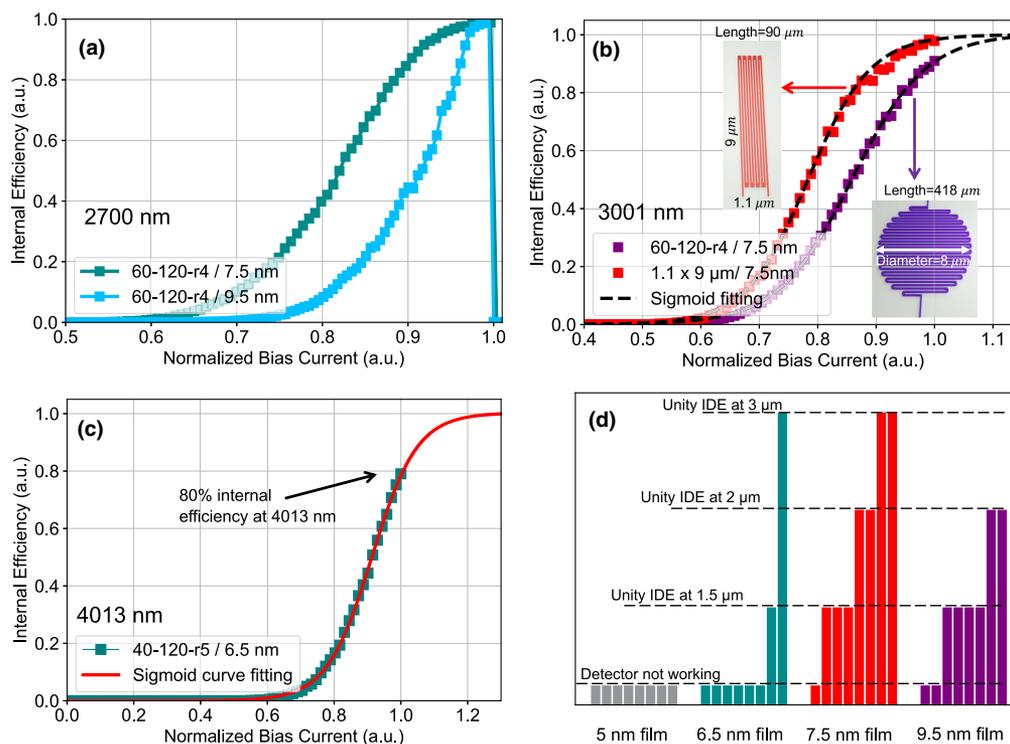
Meander Structure	$I_c$ ( $\mu\text{A}$ )		Rise Time (ps)		Dead Time (ns)		Jitter (ps)	
	9.5 nm	7.5 nm	9.5 nm	7.5 nm	9.5 nm	7.5 nm	9.5 nm	7.5 nm
80-160-r4.5	25.0	18.4	350	375	9.3	10.6	30	44
60-120-r4	18.2	14.0	325	335	11.6	12.6	40	45
40-80-r5	8.4	6.0	400	425	38.4	49.2	93	97

The above results show that saturated internal efficiency until 2000 nm can be obtained with detectors made from 9.5/7.5 nm thick films. In order to explore the internal saturation limit, we carried out longer wavelength flood illumination measurements at 2700 and 3001 nm for a number of selected detectors. Figure 3(a) shows detectors with 60-120-r4 meander design from both 9.5/7.5 nm films at 2700 nm. Both detectors reach unity internal efficiency and detectors from 7.5 nm film (dark green curve) show stronger saturated internal efficiency than detectors from 9.5 nm film (light blue curve). This is because by reducing the thickness of the superconducting film, the superconducting energy gap is reduced with the same input photon power, and it is easier to break the superconducting state and form a resistive region [36].

Previous measurements at 2700 nm indicate that detectors made from 7.5 nm films are still promising for detecting single photons beyond 2700 nm, and we fabricated two types of SNSPDs from a 7.5 nm NbTiN film and measured their detection performances at 3001 nm. As shown in Fig. 3(b), a “large” meandering nanowire detector design of 60-120-r4

(purple), and a “small” detector design with linewidth 60 nm, filling factor 50%, and  $1.1 \mu\text{m} \times 9 \mu\text{m}$  in size (red) were employed. Based on the sigmoid-curve efficiency fitting (black dashed lines), the smaller detector shows superior saturated internal efficiency over the larger one at 3001 nm. According to a previous study [37], the performance of SNSPDs is influenced by the inhomogeneity of the superconducting film. Since the total length of the small detector ( $\sim 90 \mu\text{m}$ ) is more than 3 times shorter than that of the large one ( $\sim 418 \mu\text{m}$ ), less inhomogeneity can be expected, and better detection performance is observed. This shows that by reducing SNSPD’s total length, better detection performance can be potentially achieved. In previous works [29], the best performing device was a single  $10\text{-}\mu\text{m}$ -long line. As a consequence the active area is smaller, which can be increased by using different detector architectures; for example, multi-pixel [38] or interleaved nanowire designs [39].

Finally, we evaluated detectors made from even thinner films (5 and 6.5 nm). In Fig. 3(c), we demonstrate that a detector (40-120-r5) from 6.5 nm film achieves 80% internal



**Fig. 3.** (a) Photon counting rate (PCR) curves at 2700 nm of 60-120-r4 detectors from 7.5 nm (green) and 9.5 nm (blue) films, (b) PCR curves at 3001 nm of a 60-120-r4 detector/purple and a  $1.1 \mu\text{m} \times 9 \mu\text{m}$  detector/red from 7.5 nm films, (c) PCR curves at 4013 nm of a 40-120-r5 detector from 6.5 nm film, and (d) yield statistics of devices made from films with different thicknesses.

efficiency at 4013 nm (determined using a sigmoid curve fitting). This represents the state-of-the-art mid-infrared polycrystalline-material-based SNSPDs. To get a better understanding of the film thickness effect on the detector performance, we created an overview in Fig. 3(d). We present the statistics of 32 fabricated SNSPDs from four different films. It is clear that 5 and 6.5 nm films suffer from low yield. The detectors made from the 5 nm films do not work well, because of their low critical current (1–2  $\mu\text{A}$ ). The non-working detectors from the 6.5 nm film did not show unity internal efficiency at 1550 nm and this is possibly caused by lower film homogeneity of the thin film [19]. In contrast, 7.5 and 9.5 nm films show higher yield but detectors from the 9.5 nm film start to show decreased internal efficiency in the mid-infrared compared to detectors from the 7.5 nm film. These results can be intuitively interpreted in such a way that thin films have less uniformity than thicker films, thus leading to a decreased yield. Thicker films are potentially more robust to local variations of surface and superconducting properties (due to magnetic contamination or variation of crystal properties) by offering an averaging effect (i.e., more atomic layers of superconducting materials). However, thicker films have larger superconducting energy gap, which lowers the internal efficiency at longer wavelengths. Various superconducting material related analyses need to be carried out in the future to establish clear correlation between superconducting property and detector yield, for example, X-ray diffraction and transmission electron microscopy for crystal structure analysis, scanning tunneling microscopy for electron states analysis, and cryogenic electric transport measurements for superconducting property analysis. Here, we also suggest two practical solutions to solve the trade-off between film thickness and performance for future mid-infrared SNSPDs study: bias-assisted sputtering can be applied to improve the critical current of SNSPDs [40] and post-processing treatment (for example, helium ion irradiation [41]) can enhance the internal efficiency of SNSPDs made from thicker films.

#### 4. MEASUREMENTS OF FIBER-COUPLED SNSPDs

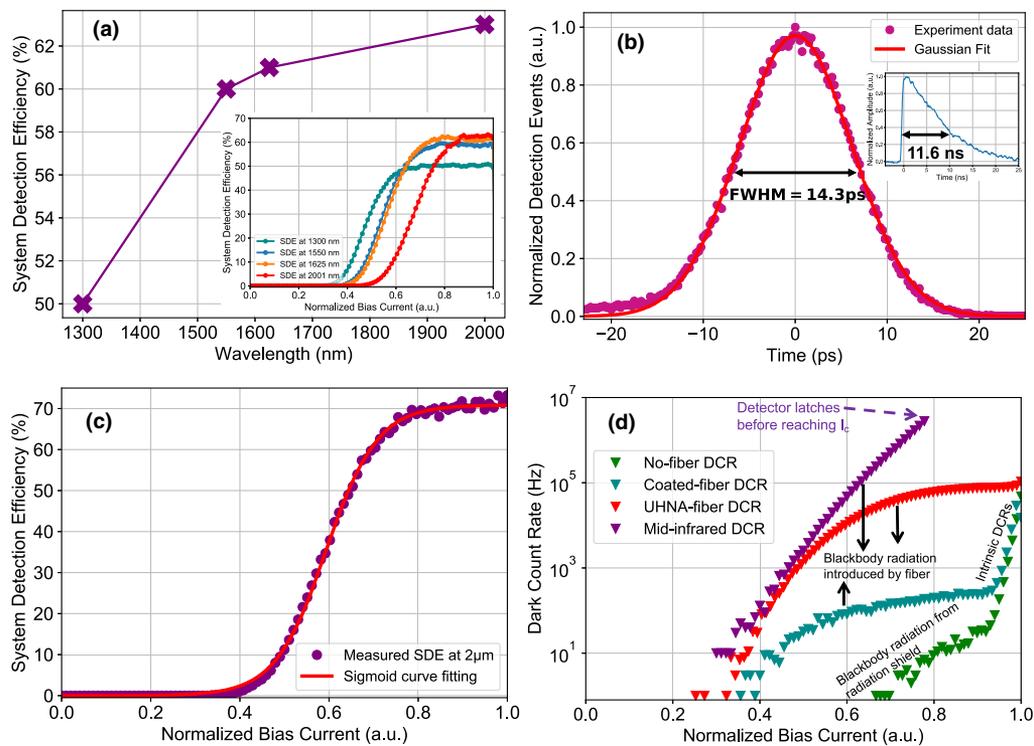
For most quantum optics experiments and applications, a fiber-coupled detector/system is preferred because of mature fiber optics technology and instruments.

The previous section provides evidence that both 7.5 and 9.5 nm NbTiN superconducting films are suitable for making mid-infrared SNSPDs in terms of good yield and internal efficiency while a reduced thickness (5–6.5 nm) leads to fewer working devices. Thus, we fabricated fiber-coupled SNSPDs from 7.5 nm thick NbTiN films. Similar to Ref. [14], the NbTiN films were initially deposited on  $\text{SiO}_2$  grown by thermal oxidation process and nanowire meanders were eventually located on top of an Au/ $\text{SiO}_2$  membrane acting as optical cavity. After packaging and wire bonding, detectors were mounted in a closed-cycle cryocooler with a base temperature of 2.4–2.8 K and coupled to single-mode fibers. Afterwards, lasers with different wavelengths were used for SDE measurements as described in the previous section.

Figure 4(a) shows the performance of detector #1 (60 nm linewidth) made from a 7.5 nm NbTiN film. The SDEs for

1300, 1550, 1625, and 2000 nm are 50%, 60%, 61%, and 63%, respectively. The inset in Fig. 4(a) shows detector #1's photon counting rate (PCR) curves at several wavelengths. Besides high SDE, high timing resolution is also highly desirable for many applications, for example, LiDAR [8] and fluorescence microscopy and spectroscopy [2,3]. The instrument response function (IRF) of detector #1 was characterized with a picosecond (ps)-pulsed laser (4.2 ps pulse width at 1064 nm wavelength) and a fast oscilloscope (4 GHz bandwidth, 40 GHz sampling rate) as described in Ref. [14]. As shown in Fig. 4(b), using a low-noise cryogenic amplifier operated at 40 K, the IRF of this device shows a Gaussian-shaped histogram. After fitting, we obtain  $14.3 \pm 0.1$  ps timing jitter (full width at half-maximum, FWHM). Compared to previous reported values for mid-infrared SNSPDs [26], we improved time resolution by nearly 2 orders of magnitude. We would also like to point out that the 14.3 ps jitter was measured with a 1064 nm pulse laser, and as demonstrated in a previous study [20], although the jitter increases with a decrease in the photon energy, the increase in jitter due to change in photon energy comparing to the other jitter contributions such as electronic jitter and geometrical jitter (for a detector with a total jitter of  $>14$  ps) is insignificant. The inset picture in Fig. 4(b) shows the pulse trace of detector #1. It shows a dead time of 11.6 ns, indicating good performance at high count rates [42]. Similarly, in Fig. 4(c), we show the 2000 nm SDE measurement of detector #2, which is made from another 7.5 nm NbTiN film but has a slightly higher meander filling factor (approximately 10% higher). The benefit of a higher filling factor is an increased optical absorption, which means if the internal efficiency is saturated, a higher SDE can be achieved compared to a similar device with a lower filling factor. As can be seen, detector #2 shows well-saturated internal efficiency (when  $I_b \geq 0.8I_c$ ). After sigmoid fitting (to improve the efficiency estimation accuracy), we obtained a peak SDE over 70% at 2000 nm.

Besides achieving high system detection efficiency, high DCRs of mid-infrared SNSPDs are a major challenge. Previous work [19] showed that the DCRs of mid-infrared SNSPDs are typically in the order of  $10^4$  Hz without using additional filters. In Fig. 4(d), we systematically studied the DCRs of detector #2 in four different schemes: DCR without any fiber connected to the detector (green curve), DCR with end-face coated SM2000 fiber (fiber operating wavelength 1.7–2.3  $\mu\text{m}$ , cyan curve), DCR with ultrahigh NA fiber without coating (fiber operating wavelength 1.5–2  $\mu\text{m}$ , red curve), and DCR with mid-infrared  $\text{ZrF}_4$  fiber without coating (fiber operating wavelength 2.3–4.1  $\mu\text{m}$ , purple curve). As a result, at  $I_b = 0.8I_c$ , the DCRs of detector #2 for the abovementioned four schemes are around the order of  $10^1$  Hz,  $10^2$  Hz,  $10^5$  Hz, and  $10^6$  Hz, respectively. It is clear that the DCR of detector #2 when coupled to an end-face coated fiber is 3 orders of magnitude lower than coupled to ultrahigh NA fiber without coating. By using this fiber end-face coating (low-pass filter), the DCR of detector #2 is below 240 Hz when it reaches unity internal efficiency at 2000 nm. In contrast, when detector #2 is connected to mid-infrared  $\text{ZrF}_4$  fiber for SDE measurements at 3–4  $\mu\text{m}$ , the detector shows over 2.78 MHz DCR at  $0.8I_c$  bias and starts latching [43]. This prevents further SDE



**Fig. 4.** Fiber-coupled SNSPDs measurements of (a) SDE of detector #1 at 1310, 1625, 1550, and 2000 nm, (b) timing jitter of detector #1, (c) SDE of detector #2 at 2001 nm, and (d) DCRs of detector #2 under different conditions: no fiber (green), low-pass coated fiber (turquoise), UHNA fiber (red), and mid-IR fiber (purple) plugged in.

measurements of detector #2 at 3–4  $\mu\text{m}$ . To solve this issue, low-pass filters should be employed before the detectors, either by using fiber end-face coating or adding cold filtering stages inside the cryostat [44].

## 5. DISCUSSION AND CONCLUSION

In the past, amorphous materials were mainly used for mid-infrared single-photon detection motivated by the intuition that their superconducting energy gap (0.59–0.61 meV for WSi [45]) is lower than polycrystalline material (2.46 meV for NbN [46]). This work pinpoints that NbTiN (polycrystalline)-based SNSPDs can also achieve high mid-infrared single-photon detection efficiency while maintaining unprecedented time resolution. Furthermore, given that the energy of a single photon even at 10  $\mu\text{m}$  wavelength (123.9 meV) is still significantly larger than both materials' superconducting energy gap, other physical properties of the superconducting materials need to be investigated to enhance SNSPDs' mid-infrared detection response. Besides improving internal detection efficiency, reducing the DCRs is another outstanding challenge for mid-infrared SNSPD systems. As shown in this work, only room temperature blackbody radiation delivered to the detector by ZrF<sub>4</sub> fiber has led to  $> 10^6$  Hz DCR. To overcome this issue, either extra cryogenic filters need to be added before the detectors or the entire experiment has to be performed at cryogenic temperatures.

In conclusion, we demonstrated SNSPDs made from magnetron co-sputtered NbTiN superconducting films (5–9.5 nm

with unity internal efficiency at 3  $\mu\text{m}$  and 80% internal efficiency at 4013 nm when operated in closed-cycle Gifford-McMahon coolers (2.4–2.8 K). Our fiber coupled device achieves over 70% system detection efficiency at 2  $\mu\text{m}$  and  $> 50\%$  system detection efficiency from 1300 to 2000 nm with sub-15 ps time resolution. By employing an end-face coated fiber, the dark count rate of mid-infrared SNSPDs was reduced by 3 orders of magnitude compared to uncoated single-mode fibers. The DCR when coupled to mid-infrared ZrF<sub>4</sub> fiber is also studied, which offers valuable information for building mid-infrared fiber-coupled SNSPDs systems in the future. To the best of our knowledge, the detectors presented in this work have the best system detection efficiency and temporal resolution among the mid-infrared SNSPDs reported so far, and NbTiN is a solid choice for making mid-infrared SNSPDs without milliKelvin dilution refrigerators.

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**Data Availability.** Data underlying the results presented in this paper are not publicly available at this time but may be obtained from the authors upon reasonable request.

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